

Daisuke Tahara

List of Publications by Year in descending order

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11

papers

292

citations

1163117

8

h-index

1372567

10

g-index

11

all docs

11

docs citations

11

times ranked

277

citing authors

#	ARTICLE	IF	CITATIONS
1	Epitaxial growth of β -(Al _x Ga _{1-x}) ₂ O ₃ alloy thin films on spinel substrates via mist chemical vapor deposition. <i>Journal of Alloys and Compounds</i> , 2021, 851, 156927.	5.5	14
2	Phase control of \pm - and β -Ga ₂ O ₃ epitaxial growth on LiNbO ₃ and LiTaO ₃ substrates using \pm -Fe ₂ O ₃ buffer layers. <i>AIP Advances</i> , 2020, 10, .	1.3	18
3	van der Waals epitaxy of ferroelectric μ -gallium oxide thin film on flexible synthetic mica. <i>Japanese Journal of Applied Physics</i> , 2020, 59, 025503.	1.5	15
4	Single-Domain and Atomically Flat Surface of β -Ga ₂ O ₃ Thin Films on FZ-Grown μ -GaFeO ₃ Substrates via Step-Flow Growth Mode. <i>ACS Omega</i> , 2020, 5, 29585-29592.	3.5	24
5	A preliminary study on mist CVD-derived ferroelectric Hf _{1-x} Zr _x O ₂ films featuring its possibility of suitable operation for non-volatile analog memory. <i>Japanese Journal of Applied Physics</i> , 2020, 59, SPPB09.	1.5	5
6	Mist chemical vapor deposition study of 20 and 100 nm thick undoped ferroelectric hafnium oxide films on n+-Si(100) substrates. <i>Japanese Journal of Applied Physics</i> , 2019, 58, SLLB10.	1.5	2
7	Heteroepitaxial growth of μ -(Al _x Ga _{1-x}) ₂ O ₃ alloy films on c-plane AlN templates by mist chemical vapor deposition. <i>Applied Physics Letters</i> , 2018, 112, .	3.3	59
8	Microstructures and rotational domains in orthorhombic μ -Ga ₂ O ₃ thin films. <i>Japanese Journal of Applied Physics</i> , 2018, 57, 115601.	1.5	61
9	Use of mist chemical vapor deposition to impart ferroelectric properties to μ -Ga ₂ O ₃ thin films on SnO ₂ /c-sapphire substrates. <i>Materials Letters</i> , 2018, 232, 47-50.	2.6	26
10	Epitaxial growth of \pm -Ga ₂ O ₃ thin films on a-, m-, and r-plane sapphire substrates by mist chemical vapor deposition using \pm -Fe ₂ O ₃ buffer layers. <i>Materials Letters</i> , 2017, 205, 28-31.	2.6	63
11	Heteroepitaxial growth of μ -Ga ₂ O ₃ thin films on cubic (111) GGG substrates by mist chemical vapor deposition. , 2017, , .	5	